

# Dual general-purpose operational amplifier

# NE/SA/SE4558

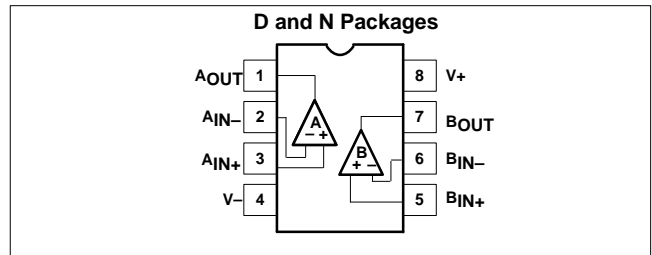
## DESCRIPTION

The 4558 is a dual operational amplifier that is internally compensated. Excellent channel separation allows the use of a dual device in a single amp application, providing the highest packaging density. The NE/SA/SE4558 is a pin-for-pin replacement for the RC/RM/RV4558.

## FEATURES

- 2MHz unity gain bandwidth guaranteed
- Supply voltage  $\pm 22V$  for SE4558 and  $\pm 18V$  for NE4558
- Short-circuit protection
- No frequency compensation required
- No latch-up
- Large common-mode and differential voltage ranges
- Low power consumption

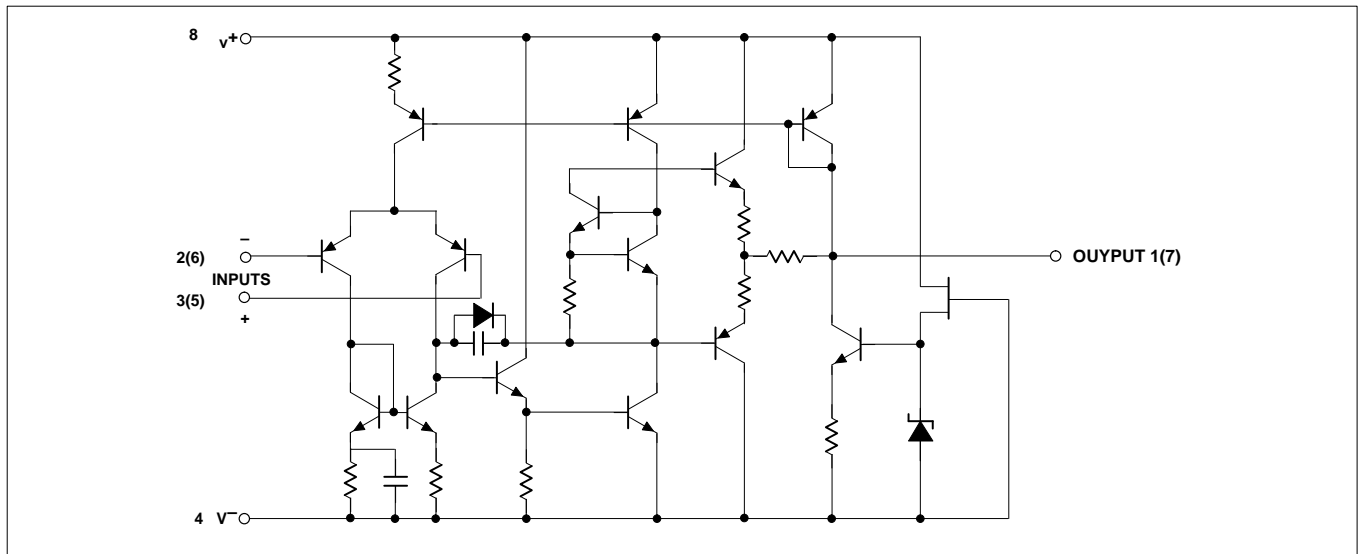
## PIN CONFIGURATIONS



## ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
8-Pin Plastic Small Outline (SO) Package	0 to +70°C	NE4558D	0174C
8-Pin Plastic Dual In-Line Package (DIP)	0 to +70°C	NE4558N	0404B
8-Pin Plastic Dual In-Line Package (DIP)	-40 to +85°C	SA4558N	0404B
8-Pin Plastic Dual In-Line Package (DIP)	-40 to +85°C	SA4558D	0404B
8-Pin Plastic Dual In-Line Package (DIP)	-55 to +125°C	SE4558N	0404B

## EQUIVALENT SCHEMATIC



## Dual general-purpose operational amplifier

NE/SA/SE4558

## ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V <sub>CC</sub>	Supply voltage		
	SE4558	±22	V
	NE4558, SA4558	±18	V
P <sub>D MAX</sub>	Maximum power dissipation,		
	T <sub>A</sub> =25°C (Still air) <sup>1</sup>		
	N package	1160	mW
	D package	780	mW
	Differential input voltage	±30	V
V <sub>IN</sub>	Input voltage <sup>2</sup>	±15	V
T <sub>STG</sub>	Storage temperature range	-65 to +150	°C
T <sub>A</sub>	Operating ambient temperature range		
	SE4558	-55 to +125	°C
	SA4558	-40 to +85	°C
	NE4558	0 to +70	°C
T <sub>SOLD</sub>	Lead soldering temperature (10sec max)	300	°C
	Output short-circuit duration <sup>3</sup>	Indefinite	

## NOTES:

- Derate above 25°C at the following rates:  
N package at 9.3mW/°C  
D package at 6.2mW/°C
- For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.
- Short-circuit may be to ground on one amp only. Rating applies to +125°C case temperature or +75°C ambient temperature for NE4558 and to +85°C ambient temperature for SA4558.

## DC ELECTRICAL CHARACTERISTICS

V<sub>CC</sub>=+15V, T<sub>A</sub>= 25°C unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	SE4558			SA/NE4558			UNIT
			Min	Typ	Max	Min	Typ	Max	
V <sub>OS</sub>	Input offset voltage	R <sub>S</sub> ≤10kΩ		1.0	5.0		2.0	6.0	mV
	ΔV <sub>OS</sub> /ΔT	Over temp.		4			4		μV/°C
I <sub>OS</sub>	Input offset current			50	200		30	200	nA
	ΔI <sub>OS</sub> /ΔT	Over temp.		20			20		pA/°C
I <sub>BIAS</sub>	Input bias current			40	500		200	500	nA
	ΔI <sub>B</sub> /ΔT	Over temp.		40			40		pA/°C
R <sub>IN</sub>	Input resistance		0.3	1.0		0.3	1.0	MΩ	
A <sub>V</sub>	Large-signal voltage gain	R <sub>L</sub> ≥2kΩ V <sub>OUT</sub> =±10V	50,00	300,0		20,00	300,0		V/V
	Output voltage swing	R <sub>L</sub> ≥10kΩ R <sub>L</sub> ≥2kΩ	±12	±14		±12	±14		V
V <sub>IN</sub>	Input voltage range		±12	±13		±12	±13		V
CMRR	Common-mode rejection ratio	R <sub>S</sub> ≤10kΩ	70	100		70	100		dB
PSRR	Power supply rejection ratio	R <sub>S</sub> ≤10kΩ		10	150		10	150	μV/V
I <sub>SC</sub>	Short-circuit current		5	25	60	5	25	60	mA
	Power consumption (all amplifiers)	R <sub>L</sub> =∞		120	170		120	170	mW

## Dual general-purpose operational amplifier

NE/SA/SE4558

**DC ELECTRICAL CHARACTERISTICS** (Continued)

SYMBOL	PARAMETER	TEST CONDITIONS	SE4558			SA/NE4558			UNIT
			Min	Typ	Max	Min	Typ	Max	
$t_R$	Transient response (unity gain)	$V_{IN}=20mV$ $R_L=2k\Omega$ $C_L\leq 100pF$							
	Rise time			100			100		ns
	Overshoot			15.0			15.0		%
SR	Slew rate (unity gain)	$R_L\geq 2k\Omega$		1.0			1.0		V/ $\mu s$
	Channel separation (gain=100)	$f=10kHz$ $R_S=1k\Omega$		90			90		dB
GBW	Unity gain bandwidth (gain=1)		2.0	3.0		2.0	3.0		MHz
$\theta_M$	Phase margin			45			45		De- gree
$V_{NOISE}$	Input noise voltage	$f=1k\Omega$		25			25		nV/ $\sqrt{Hz}$
<b>NOTE:</b> The following specifications apply over operating temperature range.									
$V_{OS}$	Input offset voltage	$R_S\leq 10k\Omega$			6.0			7.5	mV
$I_{OS}$	Input offset current				500			300/500 <sup>1</sup>	nA
$I_{BIAS}$	Input bias current				1500			800/1500 1	nA
$A_V$	Large-signal voltage gain	$R_L\geq 2k\Omega$ $V_{OUT}=\pm 10V$	25,000			15,000			V/V
	Output voltage swing	$R_L\geq 2k\Omega$	$\pm 10$			$\pm 10$			V
$P_C$	Power consumption	$T_A=HIGH$ $T_A=LOW$		105	150		115	150	mW
				125	200		120	200	mW

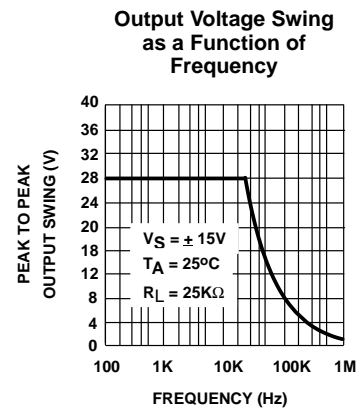
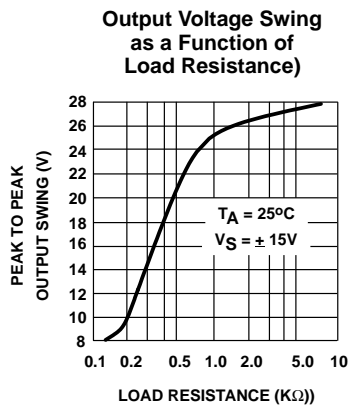
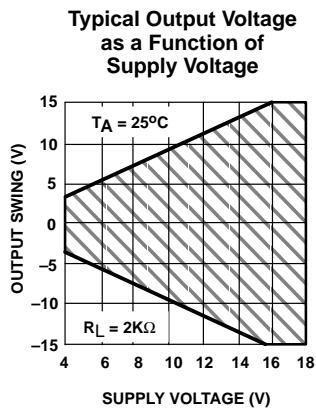
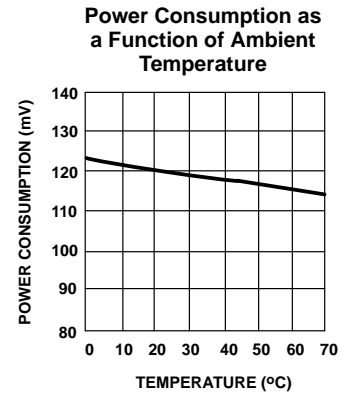
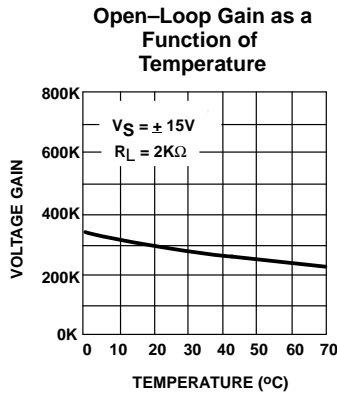
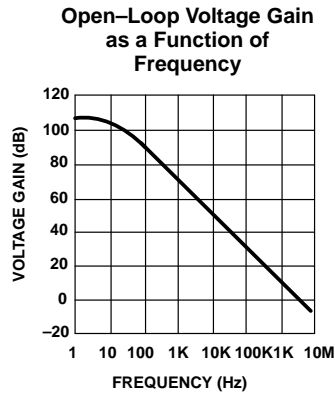
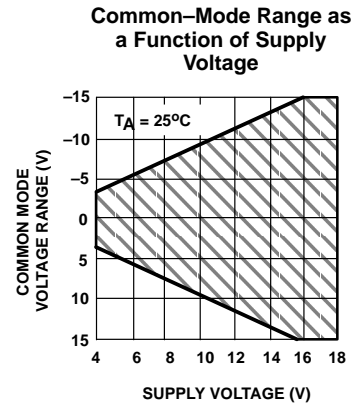
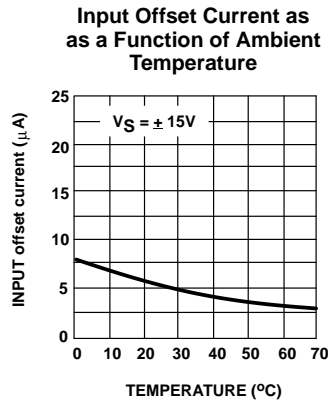
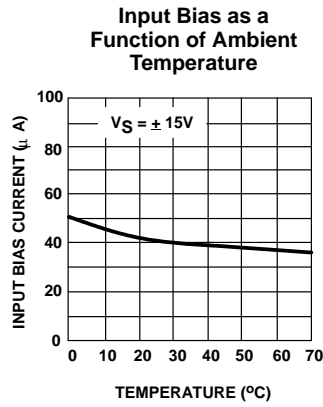
**NOTES:**

- SA4558 only.

# Dual general-purpose operational amplifier

# NE/SA/SE4558

## TYPICAL PERFORMANCE CURVES

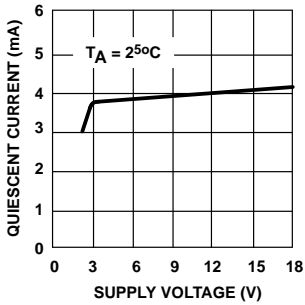


# Dual general-purpose operational amplifier

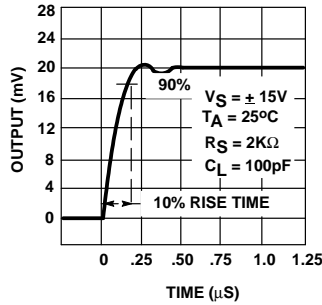
# NE/SA/SE4558

## TYPICAL PERFORMANCE CURVES (Continued)

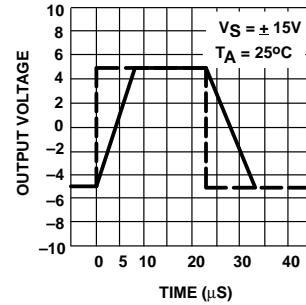
**Quiescent Current as a Function of Supply Voltage**



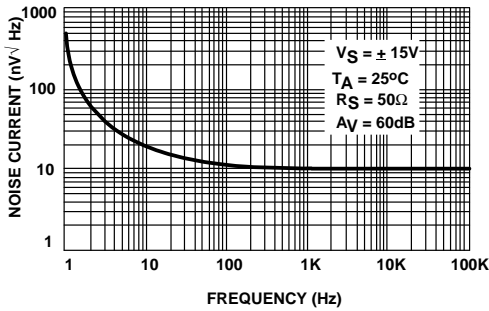
**Transient Response**



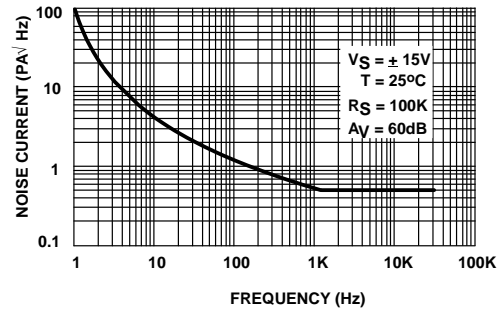
**Voltage-Follower Large-Signal Pulse Response**



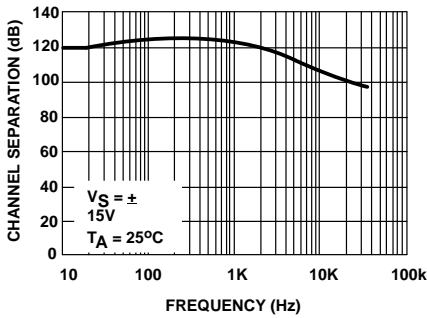
**Input Noise Voltage as a Function of Frequency**



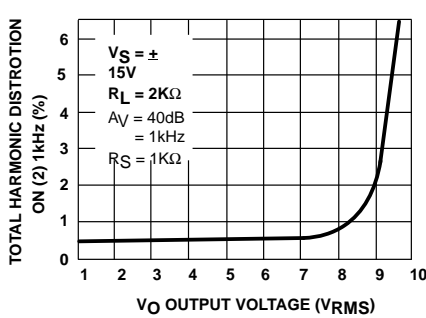
**Input Noise Current as a Function of Frequency**



**Channel Separation**



**Total Harmonic Distortion vs Output Voltage**



**Distortion vs Frequency**  
 $V_O = 1\text{V}_{\text{RMS}}$

